

TPN6R303NC,LQ

TPN6R303NC,LQ Information

Heisener.com	TPN6R303NC,LQ Toshiba Semiconductor and Storage Discrete Semiconductor Products Transistors - FETs, MOSFETs - Single MOSFET N CH 30V 20A 8TSON-ADV 8-PowerVDFN For the pricing/inventory/lead time, please contact	
For Reference Only	us Website: https://www.heisener.com E-mail: salesdept@heisener.com	Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



TPN6R303NC,LQ Specifications

Manufacturer Part Number	TPN6R303NC,LQ
Manufacturer	Toshiba Semiconductor and Storage
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	8-PowerVDFN
Series	U-MOSVIII
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	30V
Current - Continuous Drain (Id) @ 25°C	20A (Ta)
Drive Voltage (Max Rds On, Min Rds On)	4.5V, 10V
Vgs(th) (Max) @ Id	2.3V @ 200µA
Gate Charge (Qg) (Max) @ Vgs	24nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	1370pF @ 15V
Vgs (Max)	$\pm 20 \mathrm{V}$
FET Feature	-
Power Dissipation (Max)	700mW (Ta), 19W (Tc)
Rds On (Max) @ Id, Vgs	6.3 mOhm @ 10A, 10V
Operating Temperature	150°C (TJ)
Mounting Type	Surface Mount
Supplier Device Package	8-TSON Advance (3.3x3.3)
Package / Case	8-PowerVDFN
	Report errors?

TPN6R303NC,LQ Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

TPN6R303NC,LQ Payment Methods



TPN6R303NC,LQ Shipping Methods



If you have any question about TPN6R303NC,LQ, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com